## 2D Semiconducting Electronic Devices for Sensor Applications

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Flexible mobile healthcare devices showsthe most rapidly developing electronics in due to advancesin novel flexible processes, novel sensing materials, ultrathin devicesand sensors, and flexible/stretchable material. Various nanomaterials andnanostructures, including silicon nanowires (NW) and carbon nanotubes have beenactively investigated to improve the sensitivity in sensor applications. Furthermore, two-dimensional (2-D) nanomaterials, including graphene andtransition metal dichalcogenides (TMDs), have shown great potential asultra-sensitive sensors. An atomically thin active layer enables a highsurface-to-volume ratio, resulting in a superior charge sensitivity. However, theexistence of a bandgap in the TMDs unlike the zero-bandgap in graphene iscritical for the FET-based platform. In this talk, toward practical applications of 2D sensors, we will introduceseveral topics; 1) MoS2 biosensor and chemical sensor for point-of-care diagnostics,2) Novel flexible process using solution-based polymide substrate, 3) Giantphoto-amplification in multilayer 2D semiconducting phototransistors.